Increase in AC-Field Frequency and Recording Performance in Microwave-Assisted Magnetic Recording

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Magnetic recording of a hard disk drive is negatively affected by a trilemma of noise, thermal fluctuation, and writability, which prevents high recording density. Microwave-assisted magnetic recording (MAMR) is a promising recording method for solving this trilemma. In this study, methods for increasing the AC-field frequency generated from a field generation layer (FGL) and recording performance were investigated using a micromagnetic simulator in consideration of magnetic interactions of an MAMR system. Firstly, we discuss methods for increasing the frequency of the AC-field by changing saturation magnetization (M_s) of the FGL. When the M_s of the FGL decreased, the AC-field amplitude decreased and its frequency increased. When the M_s of the FGL was lower than 1.4 T, the frequency was larger than 20 GHz. Secondly, we discuss the recording performances. As a result, to improve recording performance, high frequency of AC-field (> 20 GHz) is more important than the strength of STO field.

Key words: magnetic recording, microwave-assisted recording, micromagnetic simulation, spin-torque oscillator.

1. Introduction

Hard disk drives (HDDs) have been investigated to increase their areal recording density. Recently, however, HDDs have been having simultaneous problems with noise, thermal fluctuation, and writability, commonly known as a trilemma. Microwave-assisted magnetic recording (MAMR) is a promising recording method for solving this trilemma¹⁻¹⁰⁾. In MAMR, a spin torque oscillator (STO) is placed between a conventional write head and a trailing shield. Because the AC-field generated from the field generation layer (FGL) in the STO decreases the switching magnetic fields of the medium, writability can be improved. As a result, the trilemma can be solved. Toshiba demonstrated MAMR read/write system by simulation in 2013 and experimentally demonstrated the write resolution improvement by magnetization flipped type STO in 2014^{9,10)}. HGST experimentally demonstrated MAMR gain and read/write performance in 2015¹¹⁾. Generally speaking, high frequency and large amplitude for the AC-field are necessary to improve writability. However, performances of STO placed in the write head were poorly understood. The previous paper discussed the STO thickness and magnetic properties for obtaining the strong AC-field. However the frequency was less than 15 GHz^{12,13)}.

In this study, we examined methods to increase the frequency of the AC-field and recording performance using a micromagnetic simulator that takes into account magnetic interactions between the write head, medium, and STO. As a result, when the M_s of the FGL was lower than 1.4 T, the frequency was larger than 20 GHz. To improve recording performance, high frequency of AC-field (> 20 GHz) is more important than the strength of STO field.

2. Calculation model

Fig. 1 shows the calculation model. The write head consists of a single-pole-type (SPT) head, including a main pole (MP), return pole (RP), and a trailing shield (TS). The medium consists of a soft recording layer, hard recording layer, nonmagnetic layer, and a soft under layer (SUL) and is called an exchange coupled composite (ECC) medium. The STO consists of an FGL and a spin injection layer (SIL). The head and medium was divided into 10-nm rectangular prism cells. A cell of the medium was assumed to be one grain. The STO was divided into 2.5-nm rectangular prism cells. Magnetization dynamic behavior was then calculated using a modified Landau-Lifshitz-Gilbert (LLG) equation with spin torque field (H_{st}), as shown below⁶⁾.

Fig. 1. Calculation model.

$$(1 + \alpha^2) \frac{d\mathbf{M}}{dt} = -\gamma \mathbf{M} \times (\mathbf{H}_{eff} - \alpha \mathbf{H}_{st}) - \frac{\gamma}{M_s} \mathbf{M} \times \{ \mathbf{M} \times (\alpha \mathbf{H}_{eff} + \mathbf{H}_{st}) \} \quad (1)$$

Here, $\mathbf{M}$ is the magnetization vector, $\mathbf{H}_{eff}$ is the effective field vector, α is the damping constant, γ is the gyro magnetic constant, and M_s is the saturation magnetization. The SIL was excluded from the calculation model in this study. However, the H_{st} injected from the SIL to FGL was calculated using the following equation.

$$\mathbf{H}_{st} = a_j \mathbf{M}_p = \frac{\hbar \eta J}{2eM_{sF}d} \mathbf{M}_p, \quad (2)$$

where a_j is the magnitude of the spin torque field vector, $\mathbf{M}_p$ is the direction vector of $\mathbf{H}_{st}$, $\hbar$ is Planck's constant divided by 2π , η is the spin polarizability (0.5 in this study), J is the inject current density, e is the elementary charge, M_{sF} is the saturation magnetization of the FGL, and d is the FGL thickness. Tables 1-4 show the dimensions and magnetic characteristics of head, medium, and FGL. The current in the coil was 0.18 A. As shown in Fig. 2, the coil current waveform was trapezoidal with a rise time of 0.2 ns and a cycle of 2.0 ns, corresponding to a bit length of 20 nm with the relative velocity between head and medium of 20 m/s. The spacing between the air bearing surface (ABS) and the medium surface was 5 nm. In this simulator, magnetic interactions between the write head, medium, and STO were taken into account. For instance, the AC-field was generated by the precession of the magnetization of the FGL. Basically, the precession occurs due to the balance between the external field (the head-field and stray field from the medium) and the H_{st} in the perpendicular direction (x component in Fig. 1). However, in actuality, the FGL is affected not only by the x component but also by the y and z components of the external fields. This simulator takes into account all field components and can accurately simulate the processes. Thermal fluctuation was not considered.

Table 1 Magnetic characteristics of Head.

Symbol	Quantity	Value
M_s	Saturation magnetization	2.5 T
K_u	Magnetic anisotropy	$3.0 \times 10^3 \text{ J/m}^3$
A	Exchange stiffness constant	$1.0 \times 10^{-11} \text{ J/m}$

Table 2 Magnetic characteristics of FGL.

Symbol	Quantity	Value
K_u	Magnetic anisotropy	$5.0 \times 10^3 \text{ J/m}^3$
$A_{//}$	Exchange stiffness constant	$2.0 \times 10^{-11} \text{ J/m}$

Table 3 Dimensions of head, medium, and FGL.

Quantity			Value [nm]
SPT Head	MP	Thickness	100
		Width	70
		Throat height	50
	TS	Thickness	180
		Width	540
		Height	100
	RP	Thickness	220
		Width	1000
		Height	400
Recording Medium thickness		Recording layer	10
		SUL	50
		Nonmagnetic layer	5
FGL	Width (y dir.)	30	
	Height (z dir.)	30	
	Thickness (x dir.)	20	
Spacing between MP and FGL			5
Spacing between TS and FGL			5

Table 4 Magnetic characteristics of recording layer.

Symbol	Quantity	Value
M_s	Saturation magnetization	0.8 T
K_u	Magnetic anisotropy of soft layer	$3.0 \times 10^3 \text{ J/m}^3$
K_u	Magnetic anisotropy of hard layer	$1.3 \times 10^6 \text{ J/m}^3$
$A_{//}$	Exchange stiffness constant in plane	$2.0 \times 10^{-11} \text{ J/m}$
A	Exchange stiffness constant in vertical	$1.0 \times 10^{-11} \text{ J/m}$

Table 5 Magnetic characteristics of SUL.

Symbol	Quantity	Value
M_s	Saturation magnetization	1.5 T
K_u	Magnetic anisotropy	$3.0 \times 10^3 \text{ J/m}^3$
$A_{//}$	Exchange stiffness constant in plane	$1.0 \times 10^{-11} \text{ J/m}$
A	Exchange stiffness constant in vertical	$1.0 \times 10^{-11} \text{ J/m}$

3. Methods for increasing frequency of AC-field

In this chapter, we discuss methods for increasing the frequency of the AC-field. Fig. 2 shows an example of the averaged AC-field in the cross-track direction (H_y) at 9 nm under the FGL. The averaged amplitude ($\langle H_y \rangle$) and frequency (f_{STO}) were evaluated. In this graph, circles from 0.5 to 1.0 ns and from 1.5 to 2.0 ns show sampling points to evaluate $\langle H_y \rangle$ and f_{STO} because the AC-field was disordered at the other times due to nonuniformity of the gap field during current reversal. Fig. 3 shows the M_s of the FGL dependence of $\langle H_y \rangle$ and f_{STO} at H_{st} of 80 kA/m. When M_s was less than 1.4 T, f_{STO} was larger than 20 GHz, and its maximum was 22.5 GHz at M_s of 1.2 T. However, $\langle H_y \rangle$ decreased with decreasing M_s . When M_s set 2.0 T, $\langle H_y \rangle$ was 80 kA/m. However, $\langle H_y \rangle$ was only 36 kA/m at M_s of 1.2 T. Fig. 4

shows the M_s of the FGL dependence of relative variation ($\sigma_{H_y}/\langle H_y \rangle$) at the same H_{st} in Fig. 3. When M_s was less than 1.0 T, $\sigma_{H_y}/\langle H_y \rangle$ drastically increased. In other words, when M_s was less than 1.0 T, the AC-field waveform was disordered. Therefore, the AC-field with the frequency over 20 GHz and low $\sigma_{H_y}/\langle H_y \rangle$ was obtained on condition that the M_s of the FGL was between 1.2 and 1.4 T. We then investigated the increasing method of $\langle H_y \rangle$ for M_s of 1.2 and 1.4 T. Fig. 5 shows the H_{st} dependence of $\langle H_y \rangle$ and f at the M_s of the FGL of 1.2 and 1.4 T. Here, H_{st} changed from 60 to 80 kA/m. An f_{STO} over 20 GHz was obtained when H_{st} was larger than 65 kA/m. For M_s of 1.2 T, $\langle H_y \rangle$ increased from 36 to 50 kA/m as H_{st} decreased from 80 to 65 kA/m. For the M_s of 1.4 T, $\langle H_y \rangle$ increased from 50 to 60 kA/m as H_{st} decreased from 80 to 65 kA/m. However, $\langle H_y \rangle$ was lower than the maximum value of 77 kA/m in Fig. 3.

4. Recording Performance

Okamoto et al. experimentally revealed the relation between switching field and AC-field¹⁴⁾. According this paper, the switching field monotonically decreased with increasing the frequency and field strength up to a critical frequency depending on the field strength. However, it was difficult to obtain the AC-field with high frequency and strong field, because both have a strong interaction, as shown in the chapter 3. Then, in this chapter, we discuss the recording performances of several AC-fields investigated in the previous chapter. Table 6 and Fig. 6 show recording models. We simulated a high $\langle H_y \rangle$ model ($M_s = 2.0$ T, $H_{st} = 80$ kA/m: model A, $M_s = 1.8$ T, $H_{st} = 80$ kA/m: model B, and $M_s = 1.6$ T, $H_{st} = 80$ kA/m: model C), high frequency models ($M_s = 1.4$ T, $H_{st} = 80$ kA/m: model D, and $M_s = 1.2$ T, $H_{st} = 80$ kA/m: model E), a model with over 20 GHz and maximum $\langle H_y \rangle$ model

Fig. 2 Example of sampling point of y-component of AC-field (H_y) and coil current.

Fig. 3 Averaged y-component of AC-field $\langle H_y \rangle$ vs. M_s of FGL.

Fig. 4 Normalized variance of averaged y-component of AC-field $\sigma_{H_y}/\langle H_y \rangle$ vs. M_s of FGL.

Fig. 5 Averaged y-component of AC-field $\langle H_y \rangle$ vs. H_{st} .

($M_s = 1.4$ T, $H_{st} = 65$ kA/m: model F), and a model without an FGL (Model G), which was a conventional write head for comparing the effects of the AC-field. The recording performances were evaluated using recording efficiency (RE), as shown in the following equation.

$$RE = \frac{1}{N_{smp}} \sum_{i=1}^{N_{smp}} m_{ideal}(i) \cdot m_{rec}(i) \quad (3)$$

Here, N_{smp} is the sampling number, $m_{ideal}(i)$ is the z-component of the i th sampling point for the ideal

magnetization pattern, and $m_{rec}(i)$ is that for the calculated pattern⁸⁾. The RE was from -1 to 1 . If the RE is 1 , all magnetizations of grains are saturated and the medium is ideally recorded. Figs. 7 (a) – (g) show the recorded magnetization waveforms (z-component) from models A to G. The ideal waveform is also shown in each figure. The REs from A to G were 0.51 , 0.52 , 0.65 , 0.67 , 0.83 , 0.74 , and 0.76 , respectively. As a result, the RE of only model E was higher than that of conventional write head (model G). On the other hand, the REs of models A-D and F were lower than that of the conventional write head (model G). The $\langle H_y \rangle$ values of these models were higher than that of model E, and the f_{STO} were lower than that of model E. Figs. 8 and 9 show $\langle H_y \rangle$ and f_{STO} dependence of RE, respectively. From these graphs, the REs increased with increasing f_{STO} and decreasing $\langle H_y \rangle$. Therefore, the model with low $\langle H_y \rangle$ and high f_{STO} showed a marked improvement in recording performance. As a result, to improve recording performance, high frequency of AC field (> 20 GHz) is more important than the strength of STO field.

Table 6 Recording FGL models.

Model	M_s [T]	H_{st} [kA/m]	$\langle H_y \rangle$ [kA/m]	f_{STO} [GHz]
A	2	80	77	17.5
B High $\langle H_y \rangle$	1.8	80	71	17.5
C	1.6	80	62	19.5
D High	1.4	80	51	20.0
E frequency	1.2	80	36	22.5
F $f_{STO} \geq 20\text{GHz}$ $\langle H_y \rangle_{\max}$	1.4	65	60	20.0
G Without FGL (w/o AC field)

Fig. 6 Relationship diagram of averaged y-component of AC-field $\langle H_y \rangle$ and frequency f_{STO} of each model.

Fig. 7 (a) Recording waveform of model A.

Fig. 7 (b) Recording waveform of model B.

Fig. 7 (c) Recording waveform of model C.

Fig. 7 (d) Recording waveform of model D.

Fig. 7(g) Recording waveform of model G.

Fig. 7 (e) Recording waveform of model E.

Fig. 8 Averaged y-component of STO field $\langle H_y \rangle$ vs. recording efficiency (RE).

Fig. 7 (f) Recording waveform of model F.

Fig. 9 Frequency of AC-field f_{STO} vs. recording efficiency (RE).

5. Conclusions

We investigated methods to increase the AC-field frequency and recording performance in microwave-assisted magnetic recording. The following results were obtained.

1. When the M_s of the FGL decreases, the AC-field amplitude decreases and its frequency of AC-field increases. When the M_s of the FGL is lower than 1.4 T, frequency is larger than 20 GHz.
2. To improve recording performance, high frequency of AC-field (> 20 GHz) is more important than the strength of STO field.

Acknowledgements This study was supported in part by the Storage Research Consortium (SRC), Japan.

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Received Aug. 25, 2015; Revised Oct. 30, 2015; Accepted Dec. 04, 2015